

# **Excellent Integrated System Limited**

Stocking Distributor

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Diodes Incorporated BCW68HTA

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>



**Distributor of Diodes Incorporated: Excellent Integrated System Limited** Datasheet of BCW68HTA - TRANS PNP 45V 0.8A SOT23-3 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



A Product Line of **Diodes Incorporated** 





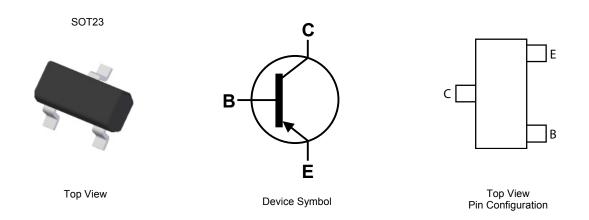
#### **45V PNP MEDIUM POWER TRANSISTOR IN SOT23**

# **Features**

- $BV_{CEO} > -45V$
- $I_C$  = -800mA high Continuous Collector Current •
- Low Saturation Voltage V<sub>CE(sat)</sub> < -300mV @ 100mA
- Complementary NPN Type: BCW66H
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

# **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight 0.008 grams (approximate)



## Ordering Information (Note 4)

P	art Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel		
BCW68HTA		DH	7	8	3,000		
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.							

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

4.1000pm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**







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BCW68H

#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

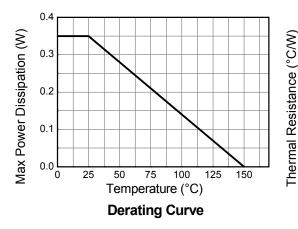
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CES</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ι <sub>C</sub>	-800	mA
Peak Pulse Current	ICM	-1000	mA
Base Current	IB	-100	mA

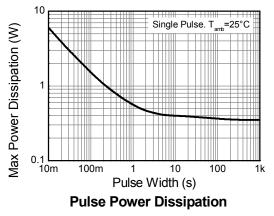
# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

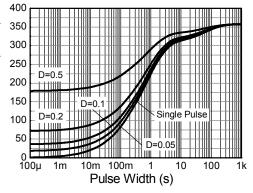
Characteristic	Symbol	Value	Unit			
Power Dissipation	(Note 5)	D-	310	mW		
	(Note 6)	PD	350	IIIVV		
Thermal Desistance Junction to Ambient	(Note 5)	<b>D</b>	403	00111		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ extsf{ heta}JA}$	357	°C/W		
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	350	°C/W		
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150	°C			

Notes: 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; the device is measured when operating in a steady-state condition. 6. Same as note (5), except the device is mounted on 15mm x 15mm FR4 PCB.

7. Thermal resistance from junction to solder-point (at the end of the leads).







**Transient Thermal Impedance** 





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Electrical Characteristics (@T <sub>A</sub> = +25°C, unless otherwise specified.)						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS				•		
Collector-Base Breakdown Voltage	BV <sub>CES</sub>	-60	_	—	V	I <sub>C</sub> = -10μΑ
Collector-Emitter Breakdown Voltage (base open) (Note 8)	BV <sub>CEO</sub>	-45	_	_	V	I <sub>CEO</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>EBO</sub> = -10μΑ
Collector-emitter cut-off current	ICES	_	<1 —	-20 -10	nA μA	V <sub>CES</sub> = -45V V <sub>CES</sub> = -45V, T <sub>A</sub> = +150°C
Emitter-base Cut-off Current	IEBO	_	<1	-20	nA	$V_{EBO} = -5.6V$

Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	—		V	I <sub>EBO</sub> = -10μA
Collector-emitter cut-off current	ICES	—	<1 —	-20 -10	nA μA	V <sub>CES</sub> = -45V V <sub>CES</sub> = -45V, T <sub>A</sub> = +150°C
Emitter-base Cut-off Current	I <sub>EBO</sub>	—	<1	-20	nA	V <sub>EBO</sub> = -5.6V
ON CHARACTERISTICS (Note 8)		÷				
Static Forward Current Transfer Ratio	h <sub>FE</sub>	250 100	350 —	630 —	—	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -1V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>			-300 —	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	—	-2	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
SMALL SIGNAL CHARACTERISTICS (Note 8)						
Transition Frequency	fT	100	—	—	MHz	I <sub>C</sub> = -20mA, V <sub>CE</sub> = -10V, f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	12	18	pF	V <sub>CB</sub> = -10V, f = 1MHz
Input Capacitance	Cibo	—	_	80	pF	V <sub>CB</sub> = -0.5V, f = 1MHz
Noise Figure	Ν	_	2	10	dB	$I_C$ = -0.2mA. V <sub>CE</sub> = -5V, R <sub>G</sub> = 1KΩ, f = 1KHz, Δf = 200Hz
Turn-On Time	t <sub>on</sub>	_	_	100	ns	$I_{\rm C} = -150 {\rm mA}.$
Turn-Off Time	t <sub>off</sub>	_	_	400	ns	I <sub>B1</sub> = -I <sub>B2</sub> = -15mA R <sub>L</sub> = 150Ω

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



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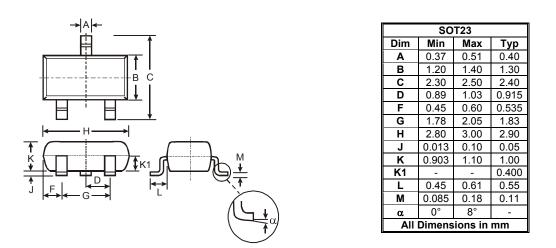


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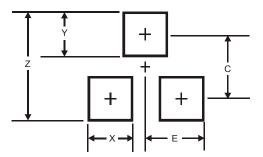
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)				
Z	2.9				
Х	0.8				
Y	0.9				
С	2.0				
E	1.35				



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BCW68H

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